

PRODUCT INFORMATION LETTER

PIL IPD-IPC/13/7674 Dated 28 Nov 2014

L7985x, L7986x: metal mask change

Sales Type/product family label	see attached list
Type of change	Product design change
Reason for change	To improve the ESD robustness.
Description	Metal fix (from BA to BB version) in order to improve the CDM immunity level.
Forecasted date of implementation	21-Nov-2014
Forecasted date of samples for customer	21-Nov-2014
Forecasted date for STMicroelectronics change Qualification Plan results availability	21-Nov-2014
Involved ST facilities	Catania, Ctm8

DOCUMENT APPROVAL

Name	Function
Merisio, Massimiliano	Marketing Manager
Merisio, Massimiliano	Product Manager
Moretti, Paolo	Q.A. Manager

A7/.

ATTACHMENT TO PIL IPD-IPC/13/7674

WHAT:

We have introduced a silicon design change through a metal mask modification, on product line UA50, upgrading from BA to BB revision.

The impacted products are:

Commercial Products	Package	Packaging type	
L7985TR	VFQFPN10		
L7986TR	VIQITIVIO		
L7985ATR		Tape & Reel	
L7986ATR			
L7986TATR	HSOP8		
L7985A	пзого		
L7986A		Tube	
L7986TA			

WHY:

To ensure a higher ESD robustness (CDM) compared to the standard qualification level.

HOW:

The change from UA50BA5 to UA50BB5 consists of a metal mask change modification in order to improve the CDM level, from the ± 300 V on all pins, to the ± 500 V on all pins and ± 750 on corner pins.

WHEN:

The metal mask change has already been evaluated on the automotive grade revision (UA50BBA, see Reliability Report RR003812CS2047) and is effective immediately.

Samples of the BB version are available upon request.



Reliability Report

General Information

Product Line UA50 BBA

Product Description Step-down switching regulator

Product division /&PC
Package /#SOP8
Silicon process technology /#BCD6s 4M

Locations

Wafer fab location CATANIA M5

Assembly plant location AMKOR ATP1

Reliability assessment Pass

DOCUMENT HISTORY

Version	Date	Pages	Author	Comment
1.0	17-12-2012	13	G.D'Angelo	Original document

Issued by Reviewed by

Gianfranco D'Angelo Alceo Paratore

Approved by

Antonino Motta

Version 1.0 Page 1/13



IPD Group – I&PC Division RELIABILITY - CASTELLETTO

Table of Contents

1	APPL	ICABLE AND REFERENCE DOCUMENTS	<i>3</i>
2	RELIA	ABILITY EVALUATION overview	4
2	2.1 OI	bjectivesbjectives	4
2	2.2 Co	onclusion	4
3	Devic	e Characteristics	5
3	3.1 D€	evice description	5
	3.1.1	Pin connection (top view)	
	3.1.2	Block diagram	
	3.1.3	Bonding diagram	7
	3.1.4	Package outline/Mechanical data	
4	Tests	results summary	10
4	1.1 T∈	est plan and results summary	10
5	Tests	Description & detailed results	11
ţ	5.1 Di	e oriented tests	11
	5.1.1	Power Temperature Cycling	11
ţ	5.2 Pa	ackage oriented tests	12
	5.2.1	Pre-Conditioning	12
	5.2.2	Thermal Cycles	12
Ę	5.3 El	ectrical Characterization Tests	13
	5.3.1	Latch-up	13
	532	ESD	13



IPD Group – I&PC Division RELIABILITY - CASTELLETTO

1 APPLICABLE AND REFERENCE DOCUMENTS

Document reference Short description

AEC-Q100 : Stress test qualification for integrated circuits 8161393A : General Specification For Product Development

Version 1.0 Page 3/13



IPD Group - I&PC Division RELIABILITY - CASTELLETTO

2 RELIABILITY EVALUATION OVERVIEW

2.1 Objectives

This report contains the reliability evaluation performed on the UA50 BBA device diffused in CATANIA M5 and assembled in HSOP8 in AMKOR ATP1, according to the AEC-Q100 (Grade1) specifications.

Considering that the device is a derivative of the full qualified U50 BAA device (see RR004611CS2047), a reduced set of trials has been performed according to the AEC-Q100 (Grade1) specifications.

Below is the list of the trials performed:

Die Oriented Tests

Power Temperature Cycling

Package Oriented Tests

- Preconditioning
- Temperature Cycling

Electrical Characterization

- ESD resistance test
- LATCH-UP resistance test

2.2 Conclusion

Taking in account the results of the trials performed the UA50 BBA diffused in CATANIA M5 and assembled in HSOP8 in AMKOR ATP1 can be qualified for automotive applications from reliability viewpoint.

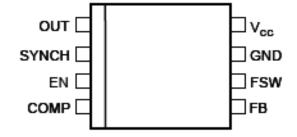
Version 1.0 Page 4/13



3 DEVICE CHARACTERISTICS

3.1 Device description

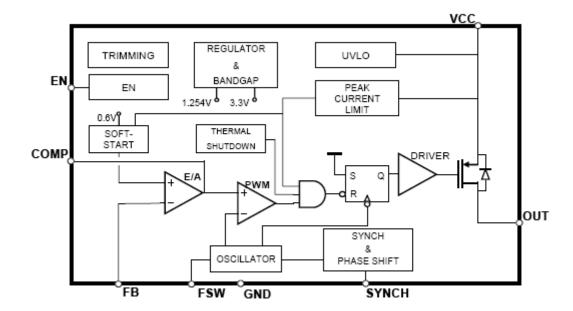
3.1.1 Pin connection (top view)



Version 1.0 Page 5/13



3.1.2 Block diagram

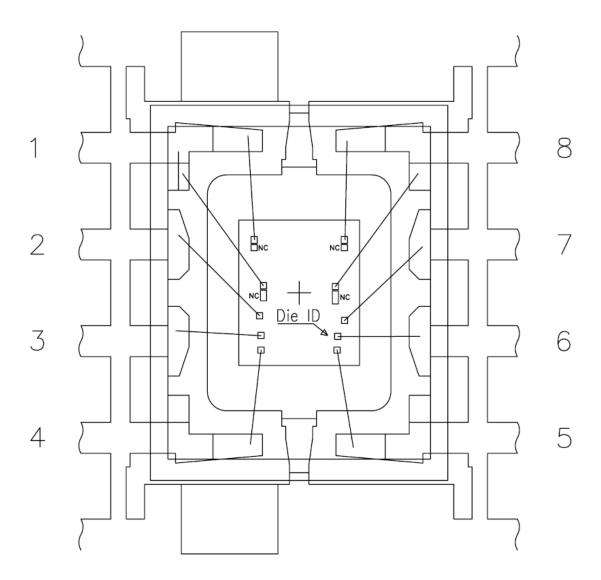


Version 1.0 Page 6/13



3.1.3 Bonding diagram

FRAME PAD : $\frac{.095 \times .122 \text{ inch}}{2.413 \times 3.099 \text{ mm}}$ Pakage: 61

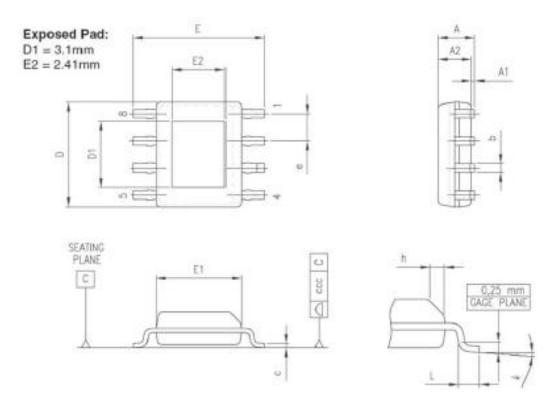


Version 1.0 Page 7/13



3.1.4 Package outline/Mechanical data

Dim		mm			inch		
Dilli	Min	Тур	Max	Min	Тур	Max	
Α			1.70			0.0669	
A1	0.00		0.15		0.00	0.0059	
A2	1.25			0.0492			
b	0.31		0.51	0.0122		0.0201	
С	0.17		0.25	0.0067		0.0098	
D	4.80	4.90	5.00	0.1890	0.1929	0.1969	
E	5.80	6.00	6.20	0.2283		0.2441	
E1	3.80	3.90	4.00	0.1496		0.1575	
е		1.27					
h	0.25		0.50	0.0098		0.0197	
L	0.40		1.27	0.0157	0.0500		
k	0		8			0.3150	
ccc			0.10			0.0039	



Version 1.0 Page 8/13



IPD Group – I&PC Division RELIABILITY - CASTELLETTO

Traceability

Wafer fab information				
Wafer fab manufacturing location	CATANIA M5			
Wafer diameter	8 inches			
Wafer thickness	375µm			
Silicon process technology	BCD6s 4M			
Die finishing back side	Cr/Ni/Au			
Die size	1909x1587μm			
Bond pad metallization layers	AlCu			
Passivation	USG+SiN+Polyimide			
Metal levels	4			

Assembly Information				
Assembly plant location	AMKOR ATP1			
Package Description	HSOP8			
Molding compound	G600			
Wires bonding materials/diameters	Au/1.2mils			
Die attach material	8290			
Lead solder material	Sn			

Version 1.0 Page 9/13





4 TESTS RESULTS SUMMARY

4.1 Test plan and results summary

Die Oriented Tests							
Test Method Conditions Sample/ Number Duration Resu							
PTC	Power Temperature Cycling						
	On Chip Boards	Tj=-40°C÷150°C Vcc=25V, lout=0.7A	45	1	1000h	PASSED	

Packag	Package Oriented Tests								
Test	Method	Conditions	Sample/ Lots	Number of lots	Duration	Results			
PC	Pre-Conditioning	Pre-Conditioning: Moisture sensitivity level 3							
		24h bake@125°C, 192h@30°C/60%R.H., Reflow Simulation (3times)	77	1		PASSED			
TC	Temperature Cyc	Temperature Cycling							
	PC before	-50°C/150°C in air	77	1	1000cy	PASSED			

Electric	Electrical Characterization Tests							
Test	Method	Conditions	Sample/ Lots	Number of lots	Duration	Results		
ESD	Electro Static Discharge							
	Human Body Model	+/- 2kV	3	1		PASSED		
	Charge Device Model	+/- 500V +/- 750V on corner pins	3	1		PASSED		
LU	Latch-Up							
	Over-voltage and Current Injection	Tamb=125°C Jedec78	6	1		PASSED		

Version 1.0 Page 10/13



IPD Group - I&PC Division RELIABILITY - CASTELLETTO

5 TESTS DESCRIPTION & DETAILED RESULTS

5.1 Die oriented tests

5.1.1 Power Temperature Cycling

This test simulates typical power automotive application. The test is addressed mainly to focus die-attach and wire bonding problems in all the temperature stress changes.

Combined stress performing an HTOL stress while the ambient temperature is cycling between -40 to +85°C (Tj=150°C) with the DUT switched alternatively ON/OFF (5'each) in asynchronous mode with respect the ambient temperature change, (1 cycle: 10' @ stress Temp. / 20' to change Temperature).

The Test Duration is 1000h

The read-outs flow chart is the following:

- Initial testing @ Ta=25°C/125°C
- Check at 168 and 500hrs @ Ta=25°C
- Final Testing (1000 hr.) @ Ta=25°C/125°C

Version 1.0 Page 11/13





5.2 Package oriented tests

5.2.1 Pre-Conditioning

The device is submitted to a typical temperature profile used for surface mounting, after a controlled moisture absorption.

The scope is to verify that the surface mounting stress does not impact on the subsequent reliability performance. The typical failure modes are "pop corn" effect and delamination.

The read-outs flow chart is the following:

- Initial testing @ Ta=25°C/125°C.
- Final Testing @ Ta=25°C/125°C.

5.2.2 Thermal Cycles

The purpose of this test is to evaluate the thermo mechanical behavior under moderate thermal gradient stress.

The read-outs flow chart is the following:

- Initial testing @ Ta=125°C.
- Check at @ 500 cycles @ Ta=25°C
- Final Testing @ 1000 cycles @ Ta=125°C.

TEST CONDITIONS:

- Ta= -50°C to +150°C(air)
- 15 min. at temperature extremes
- 1 min. transfer time

Version 1.0 Page 12/13



IPD Group - I&PC Division RELIABILITY - CASTELLETTO

5.3 Electrical Characterization Tests

5.3.1 Latch-up

This test is intended to verify the presence of bulk parasitic effects inducing latch-up.

The device is submitted to a direct current forced/sinked into the input/output pins. Removing the direct current no change in the supply current must be observed.

Stress applied setup 1 - Enable low:

condition	NEG. INJECTION	POS. INJECTION	OVERVOLTAGE
IN low: 0V	-10mA	Inom+100mA	Vcc=44V
IN high: 3.3V	-10mA	Inom+100mA	Vcc=44V

PIN 1, 4, 6 not perform trial

PIN 3 (EN) set LOW, tested only during negative trials

PIN 5 (FB) set to 1.2V

Stress applied setup 2 – Enable high:

condition	NEG. INJECTION	POS. INJECTION	OVERVOLTAGE
IN high: 3.3V	-10mA	Inom+100mA	Vcc=44V

PIN 3 (EN) set HIGH (not tested) PIN 1, 4, 5, 6 not perform trial PIN 5 set to 1.2V

The read-outs flow chart is the following:

- Initial testing @ Ta=25°C/125°C
- Latch-UP trial @ Ta=125°C
- Final Testing @ Ta=25°C/125°C

5.3.2 E.S.D.

This test is performed to verify adequate pin protection to electrostatic discharges.

The read-outs flow chart is the following:

- Initial testing @ Ta=25°C/125°C
- ESD discharging @ Ta=25°C
- Final Testing @ Ta=25°C/125°C

TEST CONDITIONS:

Human Body Model
 ANSI/ESDA/JEDEC STANDARD JES001

CDF-AEC-Q100-002

o Charge Device Model ANSI/ESD STM 5.3.1 ESDA – JEDEC JESD22-C101

CDF-AEC-Q100-011

Version 1.0 Page 13/13

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

ST PRODUCTS ARE NOT DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.

RESTRICTIONS OF USE AND CONFIDENTIALITY OBLIGATIONS:

THIS DOCUMENT AND ITS ANNEXES CONTAIN ST PROPRIETARY AND CONFIDENTIAL INFORMATION. THE DISCLOSURE, DISTRIBUTION, PUBLICATION OF WHATSOEVER NATURE OR USE FOR ANY OTHER PURPOSE THAN PROVIDED IN THIS DOCUMENT OF ANY INFORMATION CONTAINED IN THIS DOCUMENT AND ITS ANNEXES IS SUBMITTED TO ST PRIOR EXPRESS AUTHORIZATION. ANY UNAUTHORIZED REVIEW, USE, DISCLOSURE OR DISTRIBUTION OF SUCH INFORMATION IS EXPRESSLY PROHIBITED.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners

© 2014 STMicroelectronics - All rights reserved.

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

